January 17, 2008



## **DS25CP152**

## 3.125 Gbps LVDS 2x2 Crosspoint Switch

#### **General Description**

The DS25CP152 is a 3.125 Gbps 2x2 LVDS crosspoint switch optimized for high-speed signal routing and switching over lossy FR-4 printed circuit board backplanes and balanced cables. Fully differential signal paths ensure exceptional signal integrity and noise immunity. The non-blocking architecture allows connections of any input to any output or outputs.

Wide input common mode range allows the switch to accept signals with LVDS, CML and LVPECL levels; the output levels are LVDS. A very small package footprint requires a minimal space on the board while the flow-through pinout allows easy board layout. Each differential input and output is internally terminated with a  $100\Omega$  resistor to lower device return losses, reduce component count and further minimize board space.

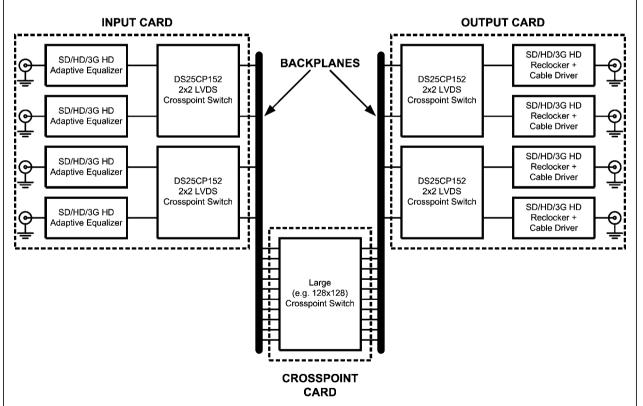
#### **Features**

- DC 3.125 Gbps low jitter, low skew, low power operation
- Pin configurable, fully differential, non-blocking architecture
- On-chip 100Ω input and output terminations minimize return losses, reduce component count and minimize board space
- 8 kV ESD on LVDS I/O pins protects adjoining components
- Small 4 mm x 4 mm LLP-16 space saving package

#### **Applications**

- High-speed channel select applications
- Clock and data buffering and muxing
- OC-48 / STM-16
- SD/HD/3G HD SDI Routers

### **Typical Application**

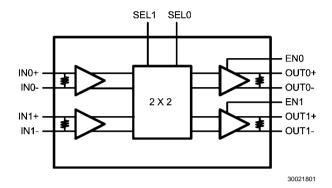


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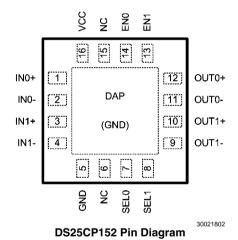
## **Ordering Code**

| NSID         | Function                   |
|--------------|----------------------------|
| DS25CP152TSQ | 2x2 LVDS Crosspoint Switch |

## **Block Diagram**



## **Connection Diagram**



## **Pin Descriptions**

| Pin Name      | Pin     | I/O, Type | Pin Description  |
|---------------|---------|-----------|--|
|               | Number  |           |  |
| IN0+, IN0- ,  | 1, 2,   | I, LVDS   | Inverting and non-inverting high speed LVDS input pins.                  |
| IN1+, IN1-    | 3, 4    |           |  |
| OUT0+, OUT0-, | 12, 11, | O, LVDS   | Inverting and non-inverting high speed LVDS output pins.                 |
| OUT1+, OUT1-  | 10, 9   |           |  |
| SEL0, SEL1    | 7, 8    | I, LVCMOS | Switch configuration pins. There is a 20 k $\Omega$ pulldown resistor on |
|               |         |           | each pin.  |
| EN0, EN1      | 14, 13  | I, LVCMOS | Output enable pins. There is a 20 kΩ pulldown resistor on each           |
|               |         |           | pin.   |
| NC            | 6, 15   | I, LVCMOS | "NO CONNECT" pins.   |
| VDD           | 16      | Power     | Power supply pin.  |
| GND           | 5, DAP  | Power     | Ground pin and Device Attach Pad (DAP) ground.                           |

## **Absolute Maximum Ratings** (Note 4)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

| Supply Voltage                                | -0.3V to +4V                 |
|---|------------------------------|
| LVCMOS Input Voltage                          | $-0.3V$ to $(V_{CC} + 0.3V)$ |
| LVDS Input Voltage                            | -0.3V to +4V                 |
| LVDS Differential Input Voltage               | 0V to 1.0V                   |
| LVDS Output Voltage                           | $-0.3V$ to $(V_{CC} + 0.3V)$ |
| LVDS Differential Output Voltage              | 0V to 1.0V                   |
| LVDS Output Short Circuit Current<br>Duration | 5 ms                         |
| Junction Temperature                          | +150°C                       |
| Storage Temperature Range                     | -65°C to +150°C              |
| Lead Temperature Range                        |                              |
| Soldering (4 sec.)                            | +260°C                       |
| Maximum Package Power Dissipation             | n at 25°C                    |
| SQA Package                                   | 2.99W                        |

| Package Thermal Resistance |           |
|----------------------------|-----------|
| $\Theta_{JA}$              | +41.8°C/W |
| $\theta_{JC}$              | +6.9°C/W  |
| ESD Susceptibility         |           |
| HBM (Note 1)               | ≥8 kV     |
| MM (Note 2)                | ≥250V     |
| CDM (Note 3)               | ≥1250V    |

Note 1: Human Body Model, applicable std. JESD22-A114C

Note 2: Machine Model, applicable std. JESD22-A115-A

Note 3: Field Induced Charge Device Model, applicable std.
JESD22-C101-C

# Recommended Operating Conditions

|  | Min | Тур | Max | Units |
|--|-----|-----|-----|-------|
| Supply Voltage (V <sub>CC</sub> )                      | 3.0 | 3.3 | 3.6 | V     |
| Receiver Differential Input Voltage (V <sub>ID</sub> ) | 0   |     | 1   | V     |
| Operating Free Air Temperature (T <sub>4</sub> )       | -40 | +25 | +85 | °C    |

#### **DC Electrical Characteristics**

Derate SQA Package

Over recommended operating supply and temperature ranges unless otherwise specified. (Notes 5, 6, 7)

23.9 mW/°C above +25°C

| Symbol           | Parameter                         | Conditions  | Min  | Тур  | Max                    | Units |  |
|------------------|-----------------------------------|---|------|------|------------------------|-------|--|
| LVCMO            | LVCMOS DC SPECIFICATIONS          |   |      |      |                        |       |  |
| V <sub>IH</sub>  | High Level Input Voltage          |   | 2.0  |      | V <sub>cc</sub>        | V     |  |
| V <sub>IL</sub>  | Low Level Input Voltage           |   | GND  |      | 0.8                    | V     |  |
| I <sub>IH</sub>  | High Level Input Current          | $V_{IN} = 3.6V$ $V_{CC} = 3.6V$                                   | 40   | 175  | 250                    | μА    |  |
| I <sub>IL</sub>  | Low Level Input Current           | $V_{IN} = GND$<br>$V_{CC} = 3.6V$                                 |      | 0    | ±10                    | μΑ    |  |
| V <sub>CL</sub>  | Input Clamp Voltage               | $I_{CL} = -18 \text{ mA}, V_{CC} = 0 \text{V}$                    |      | -0.9 | -1.5                   | V     |  |
| LVDS IN          | IPUT DC SPECIFICATIONS            |   |      |      |                        |       |  |
| V <sub>ID</sub>  | Input Differential Voltage        |   | 0    |      | 1                      | V     |  |
| V <sub>TH</sub>  | Differential Input High Threshold | $V_{CM} = +0.05V \text{ or } V_{CC} -0.05V$                       |      | 0    | +100                   | mV    |  |
| V <sub>TL</sub>  | Differential Input Low Threshold  |   | -100 | 0    |                        | mV    |  |
| V <sub>CMR</sub> | Common Mode Voltage Range         | V <sub>ID</sub> = 100 mV  | 0.05 |      | V <sub>CC</sub> - 0.05 | V     |  |
| I <sub>IN</sub>  | Input Current                     | $V_{IN} = +3.6V \text{ or } 0V$<br>$V_{CC} = 3.6V \text{ or } 0V$ |      | ±1   | ±10                    | μΑ    |  |
| C <sub>IN</sub>  | Input Capacitance                 | Any LVDS Input Pin to GND   |      | 1.7  |                        | pF    |  |
| R <sub>IN</sub>  | Input Termination Resistor        | Between IN+ and IN-   |      | 100  |                        | Ω     |  |

| Symbol           | Parameter   | Conditions                 | Min  | Тур | Max   | Units |  |
|------------------|---|----------------------------|------|-----|-------|-------|--|
| LVDS O           | LVDS OUTPUT DC SPECIFICATIONS   |                            |      |     |       |       |  |
| V <sub>OD</sub>  | Differential Output Voltage   |                            | 250  | 350 | 450   | mV    |  |
| $\Delta V_{OD}$  | Change in Magnitude of V <sub>OD</sub> for Complimentary<br>Output States | $R_L = 100\Omega$          | -35  |     | 35    | mV    |  |
| V <sub>os</sub>  | Offset Voltage  |                            | 1.05 | 1.2 | 1.375 | V     |  |
| ΔV <sub>OS</sub> | Change in Magnitude of V <sub>OS</sub> for Complimentary<br>Output States | $R_L = 100\Omega$          | -35  |     | 35    | mV    |  |
| I <sub>os</sub>  | Output Short Circuit Current (Note 8)                                     | OUT to GND                 |      | -35 | -55   | mA    |  |
|                  |   | OUT to V <sub>CC</sub>     |      | 7   | 55    | mA    |  |
| C <sub>OUT</sub> | Output Capacitance  | Any LVDS Output Pin to GND |      | 1.2 |       | pF    |  |
| R <sub>OUT</sub> | Output Termination Resistor   | Between OUT+ and OUT-      |      | 100 |       | Ω     |  |
| SUPPLY           | CURRENT   |                            |      | •   |       |       |  |
| I <sub>CC</sub>  | Supply Current  | EN0 = EN1 = High           |      | 64  | 77    | mA    |  |
| I <sub>CCZ</sub> | Supply Current with Outputs Disabled                                      | EN0 = EN1 = Low            |      | 23  | 29    | mA    |  |

Note 4: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Recommended Operating Conditions is not implied. The Recommended Operating Conditions at which the device is functional and the device should not be operated beyond such conditions.

**Note 5:** The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 6: Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except  $V_{OD}$  and  $\Delta V_{OD}$ .

Note 7: Typical values represent most likely parametric norms for V<sub>CC</sub> = +3.3V and T<sub>A</sub> = +25°C, and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.

Note 8: Output short circuit current (I<sub>OS</sub>) is specified as magnitude only, minus sign indicates direction only.

#### **AC Electrical Characteristics**

Over recommended operating supply and temperature ranges unless otherwise specified (Notes 9, 10)

| Symbol            | Parameter   | Cond                                    | itions     | Min | Тур  | Max  | Units             |
|-------------------|---|---|------------|-----|------|------|-------------------|
| LVDS OUTPU        | T AC SPECIFICATIONS   | •                                       |            | •   | •    |      | •                 |
| t <sub>PLHD</sub> | Differential Propagation Delay Low to High (Note 11)                  | $R_L = 100\Omega$                       |            |     | 340  | 500  | ps                |
| t <sub>PHLD</sub> | Differential Propagation Delay High to Low (Note 11)                  |   |            |     | 344  | 500  | ps                |
| t <sub>SKD1</sub> | Pulse Skew  t <sub>PLHD</sub> - t <sub>PHLD</sub>  <br>(Notes 11, 12) |   |            |     | 4    | 35   | ps                |
| t <sub>SKD2</sub> | Channel to Channel Skew (Notes 11, 13)                                |   |            |     | 12   | 40   | ps                |
| t <sub>SKD3</sub> | Part to Part Skew<br>(Notes 11, 14)                                   |   |            |     | 50   | 150  | ps                |
| t <sub>LHT</sub>  | Rise Time (Note 11)   | R <sub>L</sub> = 100Ω                   |            |     | 65   | 120  | ps                |
| t <sub>HLT</sub>  | Fall Time (Note 11)   |   |            |     | 65   | 120  | ps                |
| t <sub>ON</sub>   | Output Enable Time  | ENn = LH to output active               |            |     | 7    | 20   | μs                |
| t <sub>OFF</sub>  | Output Disable Time   | ENn = HL to output inactive             |            |     | 5    | 12   | ns                |
| t <sub>SEL</sub>  | Select Time   | SELn LH or HL to o                      | output     |     | 3.5  | 12   | ns                |
| JITTER PERF       | ORMANCE (Note 11)   |   |            |     |      |      |                   |
| t <sub>RJ1</sub>  | Random Jitter (RMS Value)   | V <sub>ID</sub> = 350 mV                | 2.5 Gbps   |     | 0.5  | 1    | ps                |
| t <sub>RJ2</sub>  | (Note 15)   | V <sub>CM</sub> = 1.2V<br>Clock (RZ)    | 3.125 Gbps |     | 0.5  | 1    | ps                |
| t <sub>DJ1</sub>  | Deterministic Jitter (Peak to Peak)                                   | V <sub>ID</sub> = 350 mV                | 2.5 Gbps   |     | 8    | 25   | ps                |
| t <sub>DJ2</sub>  | (Note 16)   | $V_{CM} = 1.2V$<br>K28.5 (NRZ)          | 3.125 Gbps |     | 3    | 19   | ps                |
| t <sub>TJ1</sub>  | Total Jitter (Peak to Peak)   | V <sub>ID</sub> = 350 mV                | 2.5 Gbps   |     | 0.04 | 0.08 | UI <sub>P-P</sub> |
| t <sub>TJ2</sub>  | (Note 17)   | V <sub>CM</sub> = 1.2V<br>PRBS-23 (NRZ) | 3.125 Gbps |     | 0.03 | 0.09 | UI <sub>P-P</sub> |

**Note 9:** The Electrical Characteristics tables list guaranteed specifications under the listed Recommended Operating Conditions except as otherwise modified or specified by the Electrical Characteristics Conditions and/or Notes. Typical specifications are estimations only and are not guaranteed.

Note 10: Typical values represent most likely parametric norms for  $V_{CC} = +3.3V$  and  $T_A = +25^{\circ}C$ , and at the Recommended Operation Conditions at the time of product characterization and are not guaranteed.

Note 11: Specification is guaranteed by characterization and is not tested in production.

Note 12:  $t_{SKD1}$ ,  $|t_{PLHD} - t_{PHLD}|$ , Pulse Skew, is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.

Note 13: t<sub>SKD2</sub>, Channel to Channel Skew, is the difference in propagation delay (t<sub>PLHD</sub> or t<sub>PHLD</sub>) among all output channels in Broadcast mode (any one input to all outputs).

Note 14: t<sub>SKD3</sub>, Part to Part Skew, is defined as the difference between the minimum and maximum differential propagation delays. This specification applies to devices at the same V<sub>CC</sub> and within 5°C of each other within the operating temperature range.

Note 15: Measured on a clock edge with a histogram and an acummulation of 1500 histogram hits. Input stimulus jitter is subtracted geometrically.

Note 16: Tested with a combination of the 1100000101 (K28.5+ character) and 0011111010 (K28.5- character) patterns. Input stimulus jitter is subtracted algebraically.

Note 17: Measured on an eye diagram with a histogram and an acummulation of 3500 histogram hits. Input stimulus jitter is subtracted.

## **DC Test Circuits**

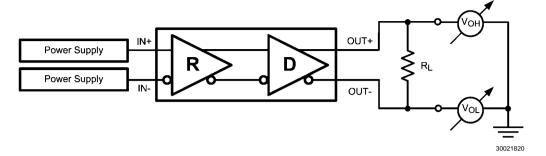


FIGURE 1. Differential Driver DC Test Circuit

## **AC Test Circuits and Timing Diagrams**

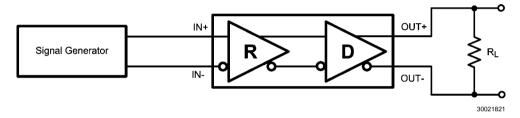


FIGURE 2. Differential Driver AC Test Circuit

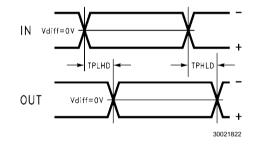


FIGURE 3. Propagation Delay Timing Diagram

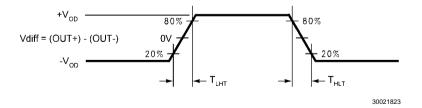


FIGURE 4. LVDS Output Transition Times

**Functional Description**The DS25CP152 is a 3.125 Gbps 2x2 LVDS digital crosspoint switch optimized for high-speed signal routing and switching

over lossy FR-4 printed circuit board backplanes and balanced cables.

#### **TABLE 1. Switch Configuration Truth Table**

| S1 | S0 | OUT1 | OUT0 |
|----|----|------|------|
| 0  | 0  | IN0  | IN0  |
| 0  | 1  | IN0  | IN1  |
| 1  | 0  | IN1  | IN0  |
| 1  | 1  | IN1  | IN1  |

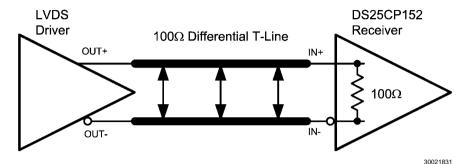
#### **TABLE 2. Output Enable Truth Table**

| EN1 | EN0 | OUT1     | ОПТ0     |
|-----|-----|----------|----------|
| 0   | 0   | Disabled | Disabled |
| 0   | 1   | Disabled | Enabled  |
| 1   | 0   | Enabled  | Disabled |
| 1   | 1   | Enabled  | Enabled  |

## **Input Interfacing**

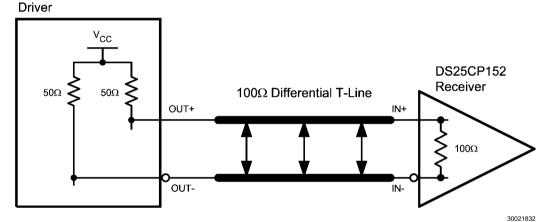
The DS25CP152 accepts differential signals and allows simple AC or DC coupling. With a wide common mode range, the DS25CP152 can be DC-coupled with all common differential

drivers (i.e. LVPECL, LVDS, CML). The following three figures illustrate typical DC-coupled interface to common differential drivers. Note that the DS25CP152 inputs are internally terminated with a  $100\Omega$  resistor.

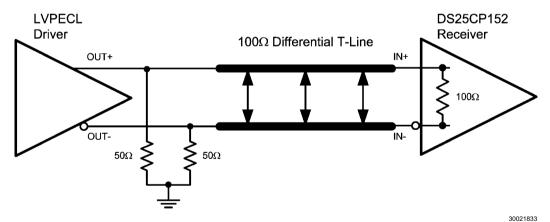


Typical LVDS Driver DC-Coupled Interface to DS25CP152 Input

CML3.3V or CML2.5V



Typical CML Driver DC-Coupled Interface to DS25CP152 Input



Typical LVPECL Driver DC-Coupled Interface to DS25CP152 Input

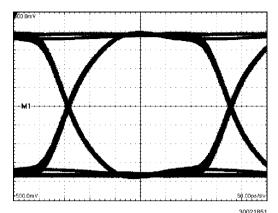
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## **Output Interfacing**

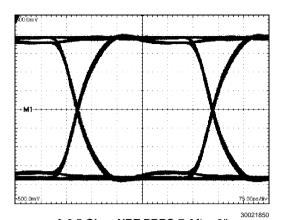
The DS25CP152 outputs signals that are compliant to the LVDS standard. Its outputs can be DC-coupled to most common differential receivers. The following figure illustrates typical DC-coupled interface to common differential receivers

and assumes that the receivers have high impedance inputs. While most differential receivers have a common mode input range that can accomodate LVDS compliant signals, it is recommended to check respective receiver's data sheet prior to

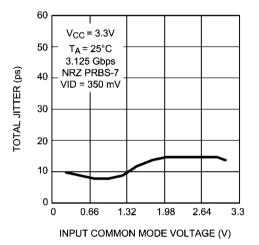
## **Typical Performance**



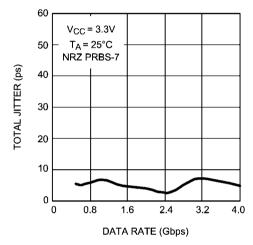
A 3.125 Gbps NRZ PRBS-7 After 2" 3002185
Differential FR-4 Stripline
V:100 mV / DIV, H:50 ps / DIV



A 2.5 Gbps NRZ PRBS-7 After 2"
Differential FR-4 Stripline
V:100 mV / DIV, H:75 ps / DIV

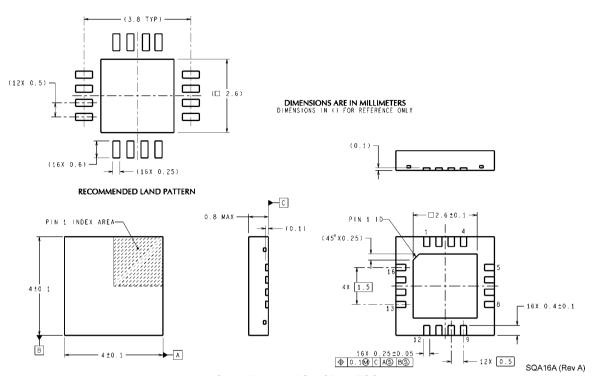


Total Jitter as a Function of Input Common Mode Voltage



Total Jitter as a Function of Data Rate

## Physical Dimensions inches (millimeters) unless otherwise noted



Order Number DS25CP152TSQ NS Package Number SQA16A (See AN-1187 for PCB Design and Assembly Recommendations)

#### **Notes**

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